

MM54HCT373/MM74HCT373 TRI-STATE® Octal D-Type Latch MM54HCT374/MM74HCT374 TRI-STATE Octal D-Type Flip-Flop

General Description

The MM54HCT373/MM74HCT373 octal D-type latches and MM54HCT374/MM74HCT374 Octal D-type flip flops advanced silicon-gate CMOS technology, which provides the inherent benefits of low power consumption and wide power supply range, but are LS-TTL input and output characteristic & pin-out compatible. The TRI-STATE outputs are capable of driving 15 LS-TTL loads. All inputs are protected from damage due to static discharge by internal diodes to V_{CC} and ground.

When the MM54HCT373/MM74HCT373 LATCH ENABLE input is high, the Q outputs will follow the D inputs. When the LATCH ENABLE goes low, data at the D inputs will be retained at the outputs until LATCH ENABLE returns high again. When a high logic level is applied to the OUTPUT CONTROL input, regardless of what signals are present at the other inputs and the state of the storage elements.

The MM54HCT374/MM74HCT374 are positive edge triggered flip-flops. Data at the D inputs, meeting the setup and hold time requirements, are transferred to the Q outputs on

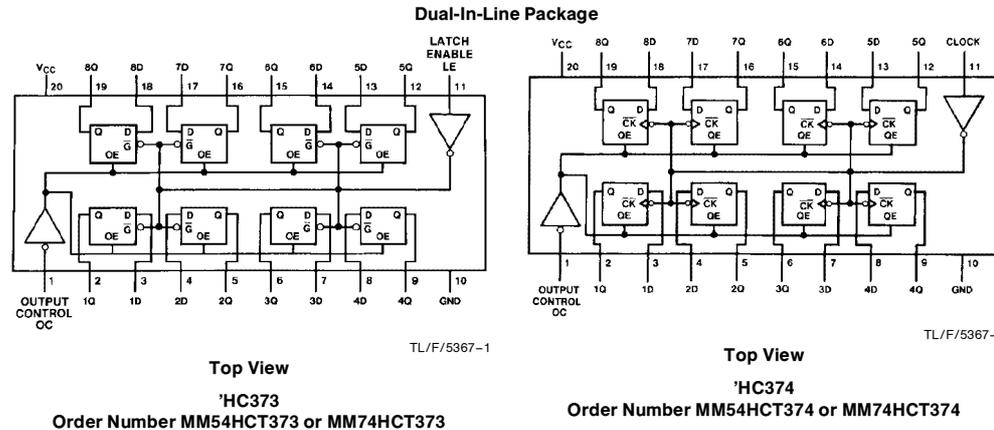
positive going transitions of the CLOCK (CK) input. When a high logic level is applied to the OUTPUT CONTROL (OC) input, all outputs go to a high impedance state, regardless of what signals are present at the other inputs and the state of the storage elements.

MM54HCT/MM74HCT devices are intended to interface between TTL and NMOS components and standard CMOS devices. These parts are also plug in replacements for LS-TTL devices and can be used to reduce power consumption in existing designs.

Features

- TTL input characteristic compatible
- Typical propagation delay: 20 ns
- Low input current: 1 μA maximum
- Low quiescent current: 80 μA maximum
- Compatible with bus-oriented systems
- Output drive capability: 15 LS-TTL loads

Connection Diagram



MM54HCT373/MM74HCT373 TRI-STATE Octal D-Type Latch
MM54HCT374/MM74HCT374 TRI-STATE Octal D-Type Flip-Flop

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Absolute Maximum Ratings (Notes 1 & 2)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage (V_{CC})	-0.5 to +7.0V
DC Input Voltage (V_{IN})	-1.5 to $V_{CC} + 1.5V$
DC Output Voltage (V_{OUT})	-0.5 to $V_{CC} + 0.5V$
Clamp Diode Current (I_{IK}, I_{OK})	± 20 mA
DC Output Current, per pin (I_{OUT})	± 35 mA
DC V_{CC} or GND Current, per pin (I_{CC})	± 70 mA
Storage Temperature Range (T_{STG})	-65°C to +150°C
Power Dissipation (P_D)	
(Note 3)	600 mW
S.O. Package only	500 mW
Lead Temp. (T_L) (Soldering 10 seconds)	260°C

Operating Conditions

	Min	Max	Units
Supply Voltage (V_{CC})	4.5	5.5	V
DC Input or Output Voltage (V_{IN}, V_{OUT})	0	V_{CC}	V
Operating Temp. Range (T_A)			
MM74HCT	-40	+85	°C
MM54HCT	-55	+125	°C
Input Rise or Fall Times (t_r, t_f)		500	ns

DC Electrical Characteristics $V_{CC}=5V \pm 10\%$ (unless otherwise specified)

Symbol	Parameter	Conditions	$T_A = 25^\circ\text{C}$		74HCT	54HCT	Units
			Typ	Guaranteed Limits			
			$T_A = -40$ to 85°C		$T_A = -55$ to 125°C		
V_{IH}	Minimum High Level Input Voltage			2.0	2.0	2.0	V
V_{IL}	Maximum Low Level Input Voltage			0.8	0.8	0.8	V
V_{OH}	Minimum High Level Output Voltage	$V_{IN} = V_{IH}$ or V_{IL} $ I_{OUT} = 20 \mu\text{A}$ $ I_{OUT} = 6.0 \text{ mA}, V_{CC} = 4.5V$ $ I_{OUT} = 7.2 \text{ mA}, V_{CC} = 5.5V$	V_{CC}	$V_{CC} - 0.1$	$V_{CC} - 0.1$	$V_{CC} - 0.1$	V
			4.2	3.98	3.84	3.7	V
			5.7	4.98	4.84	4.7	V
V_{OL}	Maximum Low Level Voltage	$V_{IN} = V_{IH}$ or V_{IL} $ I_{OUT} = 20 \mu\text{A}$ $ I_{OUT} = 6.0 \text{ mA}, V_{CC} = 4.5V$ $ I_{OUT} = 7.2 \text{ mA}, V_{CC} = 5.5V$	0	0.1	0.1	0.1	V
			0.2	0.26	0.33	0.4	V
			0.2	0.26	0.33	0.4	V
I_{IN}	Maximum Input Current	$V_{IN} = V_{CC}$ or GND, V_{IH} or V_{IL}		± 0.1	± 1.0	± 1.0	μA
I_{OZ}	Maximum TRI-STATE Output Leakage Current	$V_{OUT} = V_{CC}$ or GND Enable = V_{IH} or V_{IL}		± 0.5	± 5.0	± 10	μA
I_{CC}	Maximum Quiescent Supply Current	$V_{IN} = V_{CC}$ or GND $I_{OUT} = 0 \mu\text{A}$		8.0	80	160	μA
		$V_{IN} = 2.4V$ or $0.5V$ (Note 4)		1.0	1.3	1.5	mA

Note 1: Absolute Maximum Ratings are those values beyond which damage to the device may occur.

Note 2: Unless otherwise specified all voltages are referenced to ground.

Note 3: Power Dissipation temperature derating — plastic "N" package: -12 mW/°C from 65°C to 85°C; ceramic "J" package: -12 mW/°C from 100°C to 125°C.

Note 4: Measured per pin. All others tied to V_{CC} or ground.

AC Electrical Characteristics MM54HCT373/MM74HCT373

$V_{CC} = 5.0V$, $t_r = t_f = 6\text{ ns}$ $T_A = 25^\circ\text{C}$ (unless otherwise specified)

Symbol	Parameter	Conditions	Typ	Guaranteed Limit	Units
t_{PHL} , t_{PLH}	Maximum Propagation Delay Data to Output	$C_L = 45\text{ pF}$	18	25	ns
t_{PHL} , t_{PLH}	Maximum Propagation Delay Latch Enable to Output	$C_L = 45\text{ pF}$	21	30	ns
t_{PZH} , t_{PZL}	Maximum Enable Propagation Delay Control to Output	$C_L = 45\text{ pF}$ $R_L = 1\text{ k}\Omega$	20	28	ns
t_{PHZ} , t_{PLZ}	Maximum Disable Propagation Delay Control to Output	$C_L = 5\text{ pF}$ $R_L = 1\text{ k}\Omega$	18	25	ns
t_W	Minimum Clock Pulse Width			16	ns
t_S	Minimum Setup Time Data to Clock			5	ns
t_H	Minimum Hold Time Clock to Data			10	ns

AC Electrical Characteristics MM54HCT373/MM74HCT373

$V_{CC} = 5.0V \pm 10\%$, $t_r = t_f = 6\text{ ns}$ (unless otherwise specified)

Symbol	Parameter	Conditions	$T_A = 25^\circ\text{C}$		74HCT	54HCT	Units
			Typ	Guaranteed Limits		$T_A = -40\text{ to }85^\circ\text{C}$	
t_{PHL} , t_{PLH}	Maximum Propagation Delay Data to Output	$C_L = 50\text{ pF}$ $C_L = 150\text{ pF}$	22	30	37	45	ns
			30	40	50	60	
t_{PHL} , t_{PLH}	Maximum Propagation Delay Latch Enable to Output	$C_L = 50\text{ pF}$ $C_L = 150\text{ pF}$	25	35	44	53	ns
			32	45	56	68	
t_{PZH} , t_{PZL}	Maximum Enable Propagation Delay Control to Output	$C_L = 50\text{ pF}$ $C_L = 150\text{ pF}$ $R_L = 1\text{ k}\Omega$	21	30	37	45	ns
			30	40	50	60	
t_{PHZ} , t_{PLZ}	Maximum Disable Propagation Delay Control to Output	$C_L = 50\text{ pF}$ $R_L = 1\text{ k}\Omega$	21	30	37	45	ns
t_{THL} , t_{TLH}	Maximum Output Rise and Fall Time	$C_L = 50\text{ pF}$	8	12	15	18	ns
t_W	Minimum Clock Pulse Width			16	20	24	ns
t_S	Minimum Setup Time Data to Clock			5	6	8	ns
t_H	Minimum Hold Time Clock to Data			10	13	20	ns
C_{IN}	Maximum Input Capacitance			10	10	10	pF
C_{OUT}	Maximum Output Capacitance			20	20	20	pF
C_{PD}	Power Dissipation Capacitance (Note 5)	$OC = V_{CC}$		5			pF
		$OC = GND$		52			pF

Note 5: C_{PD} determines the no load dynamic power consumption, $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$, and the no load dynamic current consumption, $I_S = C_{PD} V_{CC} f + I_{CC}$.

Truth Table

'373

Output Control	LE	Data	373 Output
L	H	H	H
L	H	L	L
L	L	X	Q_0
H	X	X	Z

H = high level, L = low level

Q_0 = level of output before steady-state input conditions were established.

Z = high impedance

'374

Output Control	Clock	Data	Output (374)
L	\uparrow	H	H
L	\uparrow	L	L
L	L	X	Q_0
H	X	X	Z

H = High Level, L = Low Level

X = Don't Care

\uparrow = Transition from low-to-high

Z = High impedance state

Q_0 = The level of the output before steady state input conditions were established.

AC Electrical Characteristics MM54HCT374/MM74HCT374

$V_{CC} = 5.0V$, $t_r = t_f = 6 \text{ ns}$ $T_A = 25^\circ\text{C}$ (unless otherwise specified)

Symbol	Parameter	Conditions	Typ	Guaranteed Limit	Units
f_{MAX}	Maximum Clock Frequency		50	30	MHz
t_{PHL} , t_{PLH}	Maximum Propagation Delay to Output	$C_L = 45 \text{ pF}$	20	32	ns
t_{PZH} , t_{PZL}	Maximum Enable Propagation Delay Control to Output	$C_L = 45 \text{ pF}$ $R_L = 1 \text{ k}\Omega$	19	28	ns
t_{PHZ} , t_{PLZ}	Maximum Disable Propagation Delay Control to Output	$C_L = 5 \text{ pF}$ $R_L = 1 \text{ k}\Omega$	17	25	ns
t_W	Minimum Clock Pulse Width			20	ns
t_S	Minimum Setup Time Data to Clock			5	ns
t_H	Minimum Hold Time Clock to Data			16	ns

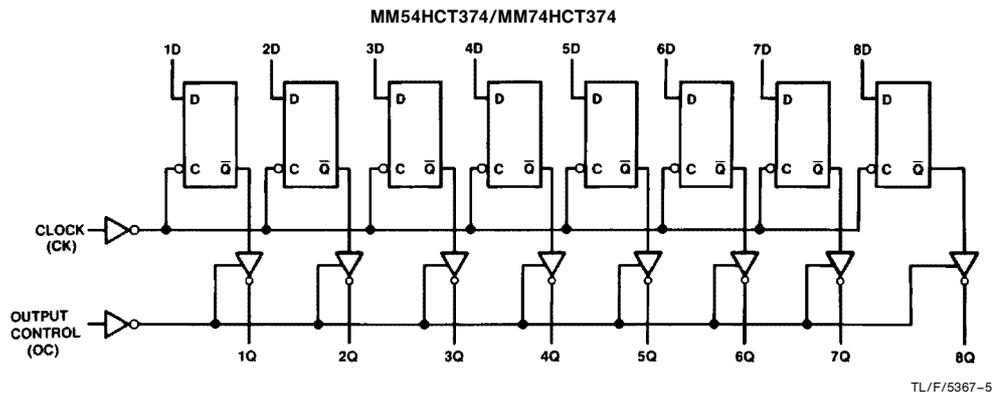
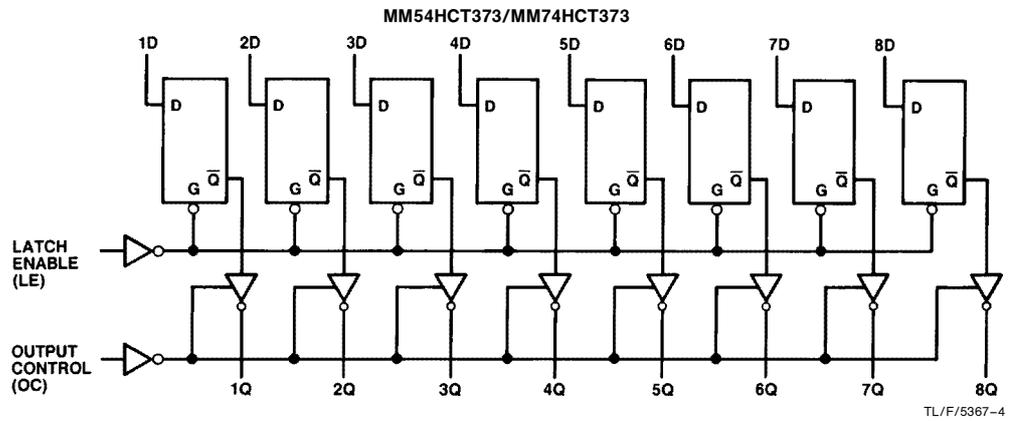
AC Electrical Characteristics MM54HCT374/MM74HCT374

$V_{CC} = 5.0V \pm 10\%$, $t_r = t_f = 6 \text{ ns}$ (unless otherwise specified)

Symbol	Parameter	Conditions	$T_A = 25^\circ\text{C}$		74HCT	54HCT	Units
			Typ	Guaranteed Limits		$T_A = -40 \text{ to } 85^\circ\text{C}$	
f_{MAX}	Maximum Clock Frequency			30	24	20	MHz
t_{PHL} , t_{PLH}	Maximum Propagation Delay to Output	$C_L = 50 \text{ pF}$ $C_L = 150 \text{ pF}$	22	36	45	48	ns
			30	46	57	69	ns
t_{PZH} , t_{PZL}	Maximum Enable Propagation Delay Control to Output	$C_L = 50 \text{ pF}$ $C_L = 150 \text{ pF}$ $R_L = 1 \text{ k}\Omega$	21	30	37	45	ns
			30	40	50	60	ns
t_{PHZ} , t_{PLZ}	Maximum Disable Propagation Delay Control to Output	$C_L = 50 \text{ pF}$ $R_L = 1 \text{ k}\Omega$	21	30	37	45	ns
t_{THL} , t_{TLH}	Maximum Output Rise and Fall Time	$C_L = 50 \text{ pF}$	8	12	15	18	ns
t_W	Minimum Clock Pulse Width			16	20	24	ns
t_S	Minimum Setup Time Data to Clock			20	25	30	ns
t_H	Minimum Hold Time Clock to Data			5	5	5	ns
C_{IN}	Maximum Input Capacitance			10	10	10	pF
C_{OUT}	Maximum Output Capacitance			20	20	20	pF
C_{PD}	Power Dissipation Capacitance (Note 5)	OC = V_{CC} OC = GND		5			pF
				58			pF

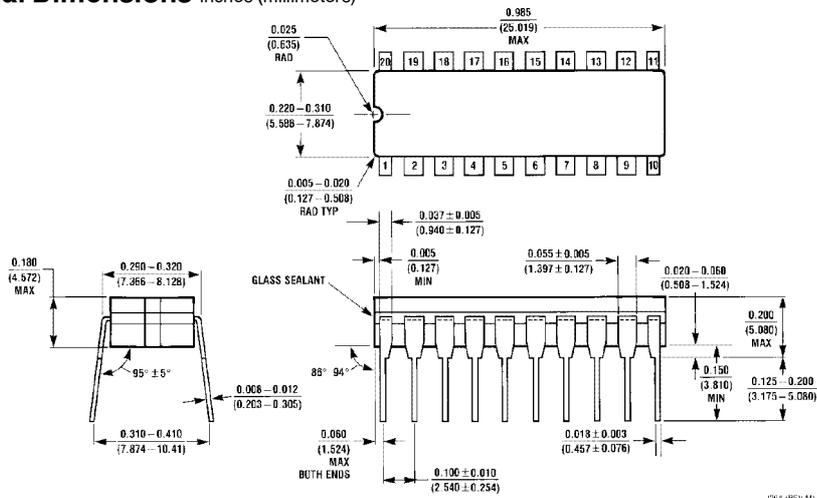
Note 5: C_{PD} determines the no load power consumption, $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$, and the no load dynamic current consumption, $I_S = C_{PD} V_{CC} f + I_{CC}$.

Logic Diagrams

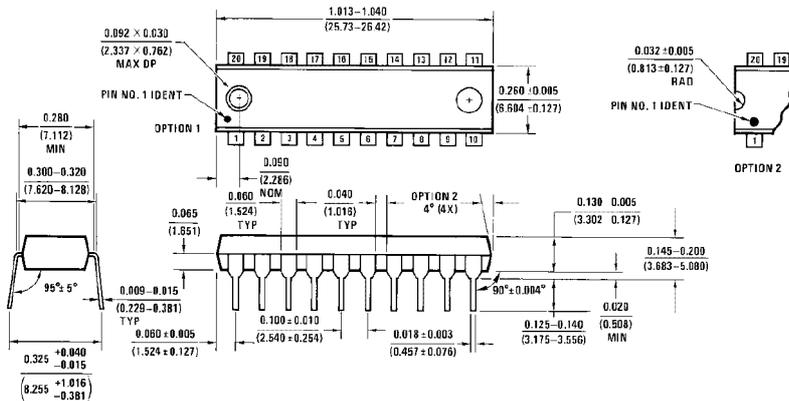


MM54HCT373/MM74HCT373 TRI-STATE Octal D-Type Latch
MM54HCT374/MM74HCT374 TRI-STATE Octal D-Type Flip-Flop

Physical Dimensions inches (millimeters)



Order Number **MM54HCT373J, MM54HCT374J, MM74HCT373J, or MM74HCT374J**
 NS Package Number **J20A**



Order Number **MM74HCT373N or MM74HCT374N**
 NS Package Number **N20A**

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